NSN 5962-01-139-3210

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View Online at https://aerobasegroup.com/nsn/5962-01-139-3210

Body Length:
Between 0.882 inches and 0.925 inches
Body Width:
0.302 inches
Body Height:
Between 0.145 inches and 0.175 inches
Maximum Power Dissipation Rating:
532.48 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and bipolar and programmable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
18 printed circuit
Shelf Life:

Demilitarization:

Unit Of Measure:

Yes - demil/mli

N/a

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